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R em arkable site selectivity properties of the ARPES matrix element in B i_2Sr_2C aC u_2O_8

S. Sahrakorpi¹, M. Lindroos^{1;2} and A. Bansil¹

¹Physics Department, Northeastern University, Boston, Massachusetts 02115

² Institute of Physics, Tam pere University of Technology, P.O. Box 692, 33101 Tam pere, Finland

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We show that the ARPES spectra for emission from the bonding as well as the antibonding Ferm i surface sheet in $B_{12}Sr_2CaCu_2O_8$ (Bi2212) possess remarkable site selectivity properties in that the emission for photon energies less than 25 eV is dominated by p! dexcitations from just the O-sites in the CuO₂ planes. There is little contribution from Cu electrons to the ARPES intensity, even though the initial states at the Ferm i energy contain an admixture of Cu-d and O-p electrons. We analyze the origin of this e ect by considering the nature of the associated dipole matrix element in detail and nd that various possible transition channels (other than p! d on O -sites) are electively blocked by either the fact that the related radial cross section is small and/or a lack of available nal states. O ur prediction that ARPES can preferentially sample Cu or O states by tuning the photon energy suggests novelpossibilities for exploiting energy dependent ARPES spectra for probing initial state characters in the cuprates.

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I. IN TRODUCTION

The photointensity observed in an angle-resolved photoem ission (ARPES) experiment is the result of modulation of the spectral density of the initial state via the ARPES matrix element. This modulation can be quite substantial in the cuprates and depends in general strongly on k_k, polarization and energy of the incident photons as well as the energy and character of the initial state.^{1,2,3,4,5,6,7,8,9} Chuang et al.⁵, for example, have recently exploited the large theoretically predicted differences in the ARPES cross sections of bonding and antibonding pieces of the Ferm i surface (FS) by tuning the photon energy to adduce the doping dependence of the bilayer splitting in Bi2Sr2CaCu2O8 (Bi2212). A sensio et al.⁴ nd that apparently di erent looking Ferm i surface m aps obtained in B i2212 over wide area in the $(k_x; k_v)$ plane at di erent photon energies largely re ect the e ect of the ARPES matrix element. In other applications, such as a recent proposal¹⁰ to determ ine the spectral function of the boson m ediating the C ooperpairs in the cuprates, it will be necessary to develop strategies form in in izing the e ect of the ARPES matrix element in order to obtain robust physical results through ARPES spectra. It is clear that a good understanding of the nature of the ARPES matrix element is of considerable im portance in continued developm ent of ARPES as a probe of electronic structure of com plex m aterials.

W ith this motivation, we exam ine in this article the nature of em issions from the bonding as well as the antibonding parts of the FS of B i2212. In considering contributions to photointensity arising from di erent angular momentum channels and various atom ic sites in the unit cell, we nd that the ARPES matrix element possesses remarkable site selectivity properties in that the ARPES intensity throughout the $(k_x; k_y)$ plane in the 5-25 eV energy range is dominated by only the O p ! d tran-

sitions. The contribution from Cu sites is quite small, even though the electronic states at the Ferm i energy in B i2212 contain substantial Cu character. In order to ascertain the origin of this e ect, the dipole transition m atrix element between the relevant initial and nalstates is analyzed in detail and the factors responsible for this behavior are identi ed.²⁷ Our prediction that ARPES can preferentially sample Cu or O states suggests novel possibilities for exploiting energy dependent ARPES spectra to gain insight into character of initial states in com plex m aterials.

The paper is ordered as follows. In Section II we brie y discuss the underlying formalism. Section III presents and analyzes the nature of the ARPES spectra. In Subsection IIIA, a typical ARPES spectrum for em ission from the Ferm i energy in Bi2212 is considered to orient the reader. Subsection IIIB continues with a discussion of site-resolved photointensities over the 5-25 eV photon energy range for kk values covering the entire $(k_x; k_y)$ plane. The origin of the site-selectivity effect is then delineated in Subsection IIIC . Finally, Section IV makes some concluding remarks, including possible application of site-selectivity property in gaining insight into interesting issues such as the Zhang-Rice mechanism 11,12 in the cuprates and the doping dependence of the Hubbard U param eter via energy dependent $ARPES m easurem ents^{13}$.

II. OVERVIEW OF FORMALISM

Them ethodology used in this study has been discussed previously in Ref. 2, to which we refer the reader for details; See also Refs. 1,14,15,16,17,18,19. Som e comment in this connection is nevertheless necessary in order to meaningfully describe the new results presented here. In particular, Ref. 2 shows that substantial insight into the nature of the ARPES photointensity²⁸ resulting from excitation between speci c bulk initial and nal states in the solid, \tilde{i} and \tilde{f} , can be obtained in terms of the behavior of the corresponding m om entum m atrix element, \tilde{f} jp $\tilde{j}_i > .$ We then expand the \tilde{i} within the KKR band structure schem $e^{20,21}$ as

$$^{\sim}(\mathbf{r}) = \int_{\mathrm{L};}^{\mathrm{A}} i^{\mathrm{I}} C_{\mathrm{L}} R_{\mathrm{1}} (\mathbf{r}) Y_{\mathrm{L}} (); \qquad (1)$$

where L (l;m) is a composite angular momentum index, Y_L () are real spherical harmonics and denotes di erent basis sites. C_L are expansion coe cients and R₁ (r) is the radial part of the B loch wave function on site . The use of form (1) for the initial and nal states yields^{2,18,19,22}

<
$${}^{\circ}_{f}\dot{p}j{}^{\circ}_{i} > = \begin{pmatrix} X & X \\ & e \\ & i^{1} {}^{1^{\circ} 1} C_{L^{\circ}} C_{L} B_{1;1^{\circ}} G_{L;L^{\circ}} : (2) \\ & ; L^{j} L^{\circ} \end{pmatrix}$$

Here \hat{e} denotes a unit vector along -direction and primed indices refer to the nalstate. $G_{L;L^0}$ are the standard G aunt coe cients. The detailed expression for B $_{1;1^0}$ is given in Ref. 2. For present purposes, the important point to recognize is that

$$B_{1;1^{0}} / R_{1^{0}} (r) r R_{1} (r) r^{2} dr;$$
 (3)

where the integral extends to the mun-tin radius r_{MT} of the atom in the basis. It is useful to decompose the momentum matrix element into contributions from various angularmomentum channels and sites in the unit cell as follows:

$$M < \tilde{f} jp j \tilde{i} > = M$$
 (4)

$$= \underset{L;L^{\circ}}{\overset{X}{\longrightarrow}} M_{;L;L^{\circ}}; \quad (5)$$

with

$$M_{;L;L^{0}} = X_{L;L^{0}} (C_{L^{0}}; C_{L^{0}}; C_{L^{0}}; C_{L^{0}}; G_{L;L^{0}}; (6)$$

A side from the obvious notation in Eqs. 4-6, indices and are together meant to encompass the summation of Eq. 2 over all basis sites in the unit cell. In the present case of tetragonal Bi2212, takes on eight distinct values which include the Ca atom and seven pairs of symmetrically located atoms (Bi, O_{Bi}, Sr, O_{Sr}, Cu, O_{Curx}, O_{Cury}). In Eq. 6, on the other hand, takes only two values, which account for the two atom s placed symmetrically with respect to the Ca layer in the unit cell. In this sense, we may think of as a \site" index and as a "pairing" index. In this work we study particularly the matrix element M_{i,Li}, which includes the contribution of pairs of sites related by mirror symmetry. We will see that its dependence on di erent sites and excitation



FIG.1: G rey scale plot (white denotes high) of theoretical ARPES intensity for emission from the Fermi energy at h = 21 eV for tetragonal Bi2212. Light is assumed to be polarized along [110] (white arrow). White and black stars give the k_k -points (corresponding to di erent angles) where the energy dependence of the dipole matrix element for the bonding (B) and antibonding (A) Fermi surface sheets shown in Figs. 2 and 3 has been computed.

channels $L ! L^0$ is in portant for delineating the nature of photointensity in Bi2212.

Concerning relevant computational details, the crystal potential used is the same as that employed in our previous studies of B i2212 on a body centered tetragonal lattice and involves 30 atoms per unit cell; See, e.g., Refs. 1 and 2. For de niteness, incident light is assumed polarized along the [110]-direction. The damping of nal states is included via an in aginary part of the nal state self-energy, ${}^{0}_{f} = 2 \text{ eV}$. In order to understand the k_k and energy dependencies of the dipole matrix element, calculations were carried out over the photon energy range of 5-25 eV for each of the 20 k_k-points considered in the (k_x; k_y)-plane. This set of k_k-points covers both the bonding and the antibonding parts of the bilayer split Ferm i surface of B i2212.

III. RESULTS

A. ARPES spectrum of Bi2212

For orientation, Fig. 1 shows a typical computed onestep ARPES spectrum for emission from the E_F at 21 eV. The Um klapp and shadow features^{3,4} are not included in this simulation for simplicity. The imprints of the bilayersplit bonding (B) and antibonding (A) parts of the FS are seen clearly and are in remarkable accord with recent ARPES experiments^{3,4,5,7,23}. The bonding band gives



FIG.2: Intensity I (Eq.7) for k_k -points (given by the angle of Fig.1) lying along the bonding and antibonding Ferm i surface sheets in tetragonal B i2212 over the photon energy range of h = 5 25 eV. Intensities have been sm oothed to re ect nal state damping e ect. Results in (a) and (b) are not norm alized in relation to each other.

rise to the X (Y) centered hole sheet B. The antibonding band is responsible for the electron-like -centered sheet A with a very narrow neck around the M -point². The associated intensity appears som ewhat di use due in part to the presence of a van Hove singularity in the electronic spectrum close to M . Note that the polarization vector of the incident light (white arrow) breaks the symmetry between the irreducible regions Υ М and М X of the Brillouin zone. For this reason, we have characterized the k-points on the A and B FS's in these two regions by the indicated angle , where > 0refers to the upper half and < 0 to the lower half on the right hand side of the gure. The intensity from either the A or the B sheet is zero along the nodal line Y (= 45), but this is not the case for the sym -

m etrically placed nodal line X for = 45. This is due to the fact that even though the momentum matrix elements M_x and M_y are non-zero in general they add (for the present polarization) destructively along Y but constructively along the X line.

As already noted, insight into the ARPES intensity can be obtained by considering the momentum matrix element < $_{\rm f}$ jp j $_{\rm i}$ > which connects the relevant initial and nal states and the associated intensity

Fig. 2 shows intensity computed by using Eq. 7 for a series of k_k -points lying along the bonding and antibonding Ferm i surface sheets characterized by the angle of Fig. 1. It is clear that the dipole matrix element varies strongly with photon energy and k_k . The main features in the intensity from both the bonding and antibonding bands are the two peaks at h around 11 eV and 18 eV.



FIG.3: Contributions to the photointensities of Fig.2 from Cu and O sites in the CuO₂ planes in the crystal lattice. (a) and (c) give contribution from Cu sites for transitions from the bonding and the antibonding initial states respectively. (b) and (d) similarly refer to the O-sites. See caption to Fig.2 for other details.

B. Contributions to photointensity from di erent sites

W e next consider the extent to which C u and O related initial state electrons are excited in the photoem ission process. Fig. 3 gives site () resolved contributions to the photointensities obtained by taking into account only the term s related to C u or O C u -sites of the C uO 2 planes, ie. for Cuor $O_{Cu;x} + O_{Cu;y}$ in Eq. 4, where the corresponding contributions from the two CuO₂ planes are added together. Fig. 3 (a) shows the Cu contribution from the bonding initial state as a function of k_k and photon energy. The intensity is seen to be practically zero indicating that, for emission emerging from any part of the bonding FS, Cu sites essentially do not contribute to the photointensity. In sharp contrast, contribution from O_{Cu} -sites in Fig. 3 (b) is substantial. In fact, the rem aining sites in the crystal lattice (not shown) are found to give little contribution, which explains why the intensity pattern from O_{Cu}-sites in Fig. 3(b) is quite similar to the corresponding total intensity in Fig. 2(a). Much of the preceding commentary concerning the bonding FS is

also seen to be valid for the antibonding FS by looking at Figs. 3(c), 3(d) and 2(b) and need not be repeated. The results of Fig. 3 thus substantially extend the observations m ade in Ref. 2 at a single k_k -value (i.e. M (;0) point) to show that the ARPES matrix element is dom inated by contribution from O_{Cu}-sites in the CuO₂ planes over the entire FS at photon energies below 25 eV. We have carried out limited computations at higher energies and nd that around h = 40 eV both Cu and O_{Cu} contribute roughly equally to the photointensity.

C. W hy copper electrons do not contribute?

Eqs. 2 and 6 m ake it clear that the value of the mom entum m atrix elem ent depends on the m agnitudes and phases of several component quantities, namely, the expansion coe cients C ' of the initial and nalstates, the Gaunt coe cients G $_{\rm L\,;L\,^{0}}$, and the radial integral term s $B_{L1^0}^{\ i}$. Concerning the character of the initial states of interest here, note that the antibonding as well as the bonding initial states in the vicinity of the FS in Bi2212 prim arily consist of electrons in the CuO₂ bilayers, where the O_{Cuix}, O_{Cuiv} and Cu atom ic sites contain approxim ately 80-90% of the weight in the associated B loch wave function². The primary Cu orbital involved is $d_{x^2 v^2}$, while the most relevant O_{Cu} orbitals are p_x and p_y . The distribution of electrons between di erent sites and orbitals changes as a function of k_k , but in general the electrons at E E_F are strongly concentrated in the vicinity of the CuO_2 planes.

Since the initial states of interest are mainly Cud and O_{Cu} p type, from various possible L ! L⁰ transition channels in Eq. 6, the dipole selection rule l = 1 lim its the L⁰ for the nal states to the Cup and f states and O_{Cu} s and d states, respectively. A handle on the availability of appropriate nal states (i.e. a substantial nal state coe cient C $i_{L_0}^{i}$) is provided by the partial densities of states (PDOS's) of the nal states resolved into di erent l⁰-channels and sites, shown in panels (a)-(d) of Fig. 4. In the case of Cu, Figs. 4(a) and 4(b) show that PDOS is substantial only in the p channel, the value in the f channel being quite sm all, so that signi cant contribution to the matrix element is to be expected only from the d! p transitions. Sim ilarly, Figs. 4 (c) and 4 (d) show that for the O_{Cu}-related nalstates, the dPDOS is substantial so that the p! d transitions from O_{Cu} -sites will dom inate. In short, the lack of Cu f-type and O_{Cu} s-type nal states in e ect \blocks" the Cud! f and O_{Cu} p ! s channels in the allowed dipole transitions such that only Cud! p and O_{Cu}p! d excitations rem ain to be of interest in further analysis.

W e next consider the term $B_{1;1^0}$ of Eq. 6 which is dened by the radial integral of Eq. 3. This term may be thought of as the radial cross section associated with site (;) for the transition from 1 to $\frac{1}{2}$ orbital. In Fig. 4 (e) these radial integrals are presented for the relevant C u



FIG.4: Left-hand side: PDOS's for nalstates are presented as a function of energy above Ferm ienergy (E_F) for the most relevant angular momentum channels. (a) and (b) show the PDOSs of Cup and f, and (c) and (d) show the O s and d nalstates. Right-hand side: (e) gives the radial integral term B; of Eq.6 for indicated 1! 1⁰ transitions from the bonding initial state at = 0 (near M -point) as a function of nal state energy. The data with crosses (squares) is for Cu (O_{Cu}) sites of the CuO₂ planes. In (f) and (g), typical initial (solid) and nal (dash-dotted) state radial wave functions R₁₀ (r) and R₁ (r), respectively, are shown as a function of radius r for O_{Cu} p ! d and Cud ! p transitions, respectively. The dotted line shows the behavior of the radial overlap integral (Eq.3).

and O_{Cu} related transitions. All curves are seen to be smooth, slow ly varying functions of energy, although absolute values vary greatly between di erent transitions. The Cud! f and $O_{Cu} p!$ dexcitation channels are the strongest, whereas the Cud! p and $O_{Cu} p!$ s integrals are sm aller and will attenuate the related excitations. In view of the discussion of the preceding paragraph, weakness of the Cud! p radial cross section is particularly in portant, since the Cud! p channel is the only Cu transition channel that could have contributed substantially to the photointensity. It follows then that the O_{Cu} p! d is the m ain transition channel in the form ation of the m om entum m atrix elem ent for em ission from the FS in B i2212 at low photon energies.²⁹

Insight into the relative m agnitudes of the O $_{Cu}$ p ! d

and Cud! p related radial cross sections can be gained by considering the behavior of initial and nal state radial wave functions as shown in panels (f) and (g) of Fig. 4. In the case of O $_{C\,u}$ p !~ d transition, initial and nal states in Fig. 4 (f) are both nodeless and thus the integral $B_{1:1^0}$ does not change sign. By contrast, the wave function for the Cup nal state in Fig. 4 (g) (dot-dashed) possesses two nodes so that when it is combined with the nodeless Cu d initial state radial wave function the integral oscillates in sign yielding a small value of the radial cross section for this transition. This mechanism where the nodes in the nal state wave function play an in portant role is rem in iscent of the argum ents m ade in connection with the origin of the Cooperm in im $a^{24,25,26}$ observed in photoionization cross sections of atom ic system s at higher photon energies.³⁰ Putting it all together, the discussion of this section shows that even though the initial states at the FS in Bi2212 possess considerable Cu d character, these states contribute little to photointen-25 eV due to a combination of two e ects: sity for h The d to f channel is suppressed due to the lack of available f-type nalstates, while the d to p channel possesses a weak radial cross section.³¹

IV. SUMMARY AND CONCLUSIONS

W e consider the nature of ARPES spectra from Bi2212 for emission from the Fermi energy. Over the 5-25 eV photon energy range, the spectra are shown to display rem arkable spatial selectivity properties in the sense that em issions are dom inated by excitation from just the 0sites in the CuO_2 planes, even though the initial state wave functions involved possess substantial Cu character. This selectivity applies to the bonding as well as the antibonding FS sheet and holds throughout the $(k_x; k_y)$ plane. Insight into the origin of this e ect is obtained by considering the dipole matrix element for transitions between the relevant initial and nal states and by decom posing this matrix element into contributions arising from individual sites in the unit cell in various angular momentum channels. Our analysis reveals that, of the two possible channels for exciting Cud-electrons (d! f and d ! p), the d ! f channel is suppressed by lack of available f-type nal states, while the d! p channel is e ectively blocked due to a small radial cross section

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(i.e. the term $B_{1;1^{\circ}}$ in Eq. 6). Sim ilarly, of the two possible channels for O p-electrons (p ! s and p ! d), the p ! s channel is suppressed since few s-type nal states are available, leaving signi cant contribution to the spectrum from only the O p ! d transitions. It turns out that the presence of nodes in the nal state wave function tends to reduce the radial cross section, which is rem iniscent of C ooper m inim um type e ect in photoionization cross section of atom ic system s. Limited com putations at higher photon energies show that the contribution from C u sites increases at higher energies, and that by around 40 eV, the C u and O states are excited roughly equally in the spectrum .

Our prediction that ARPES can preferentially sam ple Cu or O states by tuning the photon energy suggests novel possibilities for exploiting energy dependent ARPES spectra for probing initial state characters. An exciting example in the cuprates would be to test the Zhang-Ricem echanism^{11,12} and potentially to deduce experim entally the value of the Hubbard U param eter as a function of doping. Zhang and Rice noted that large U greatly restricts double occupancy of C u orbitals, so that the rst holes doped at near half lling { equivalently, the states at the top (high energy part) of the low er H ubbard band { should have strong 0 character. Thus, even though ARPES cannot see the upper Hubbard band (and hence cannot measure U directly), it should be possible to adduce U by measuring the relative Cu/O character of states along the lower Hubbard band, and com paring this to predictions of appropriate model computations. A direct determ ination of the doping dependence of U would be an important con mation of recent results and predictions¹³.

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- ²⁸ This bulk momentum matrix element of course does not take into account e ects of surface term ination, the nite lifetim es of the initial and nal states, etc.
- ²⁹ P.M arksteiner et al., Phys.Rev.B 38, 5098 (1988), considered angle-integrated photointensities and found that the spectra are weighted in favor of Cu excitations at higher photon energies.
- ³⁰ A coording to J. J. Yeh and I. Lindau, R ef. 25, the atom ic photoionization cross section is approximately one third sm aller for the Cu 3d than for the O 2p atom ic levels at photon energies around 30 eV.
- ³¹ The destructive interference discussed in Ref. 2 between C u term sofdi erent C uO ₂-planes decreases the C u-related intensity further. This destructive interference seem s to be m ore prevalent for the C u term s than for the O_{C u} -term s.